Unit: mm

## TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

# 2SD2551

# HORIZONTAL DEFLECTION OUTPUT FOR COLOR TV

• High Voltage  $: V_{CBO} = 1700 \text{ V}$ 

• Low Saturation Voltage  $: V_{CE (sat)} = 5.0 \text{ V (Max.)}$ 

• High Speed :  $t_f = 1.0 \mu s$  (Max.)

• Bult-in Damper Type

• Collector Metal (Fin) is Fully Covered with Mold Resin.

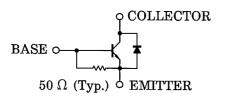
# **MAXIMUM RATINGS (Tc = 25°C)**

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Base Voltage		V <sub>CBO</sub>	1700	V	
Collector-Emitter Voltage		V <sub>CEO</sub>	600	V	
Emitter-Base Voltage		V <sub>EBO</sub>	5	V	
Collector Current	DC	IC	5	Α	
	Pulse	I <sub>CP</sub>	10		
Base Current		ΙΒ	2.5	Α	
Collector Power Dissipation		PC	50	W	
Junction Temperature		Tj	150	°C	
Storage Temperature Range		T <sub>stg</sub>	-55~150	°C	

# 1. Base 2. Collector 3. Emitter JEDEC — JEITA — TOSHIBA 2-16E3A

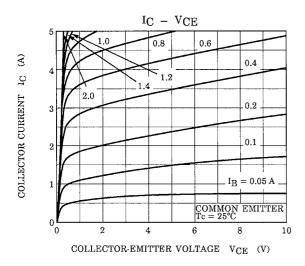
Weight: 5.5 g (typ.)

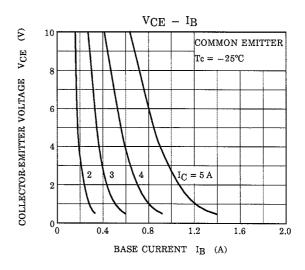
# **EQUIVALENT CIRCUIT**

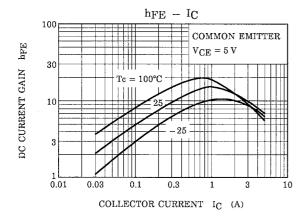


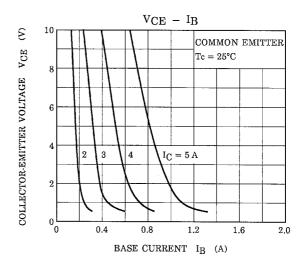
# **ELECTRICAL CHARACTERISTICS (Tc = 25°C)**

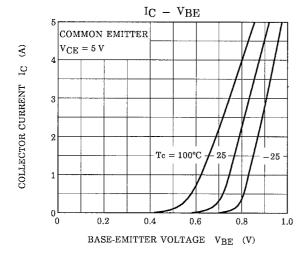
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Collector Cut-off Current		I <sub>CBO</sub>	V <sub>CB</sub> = 1700 V, I <sub>E</sub> = 0	_	_	1	mA
Emitter Cut-off Current		I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	66	_	200	mA
Emitter-Base Breakdown Voltage		V (BR) EBO	I <sub>C</sub> = 300 mA, I <sub>B</sub> = 0	5	_	_	V
DC Current Gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	8	_	28	_
DC Current Gain		h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 4 A	5	_	10	_
Collector-Emitter Saturation Voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 4 A, I <sub>B</sub> = 0.8 A	_	_	5	V
Base-Emitter Saturation Voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 4 A, I <sub>B</sub> = 0.8 A	_	_	1.5	V
Forward Voltage (Damper Diode)		V <sub>F</sub>	I <sub>F</sub> = 5 A	_	1.6	2.0	V
Transition Frequency		f <sub>T</sub>	V <sub>CE</sub> = 10 V, I <sub>C</sub> = 0.1 A	_	3	_	MHz
Collector Output Capacitance		C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	125	_	pF
Switching Time	Storage Time	t <sub>stg</sub>	I <sub>CP</sub> = 4 A, I <sub>B1</sub> (end) = 0.8 A	_	7.5	10	μs
	Fall Time	t <sub>f</sub>	f <sub>H</sub> = 15.75 kHz	_	0.5	1.0	

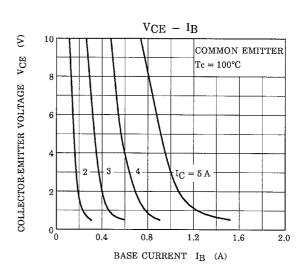




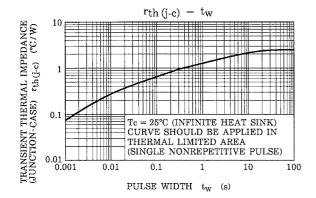


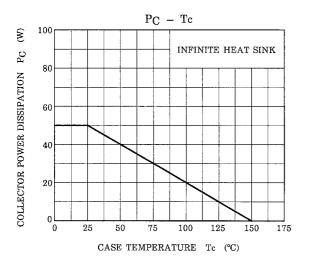


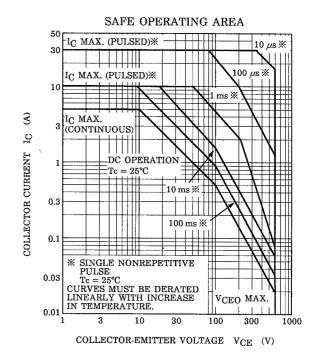




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